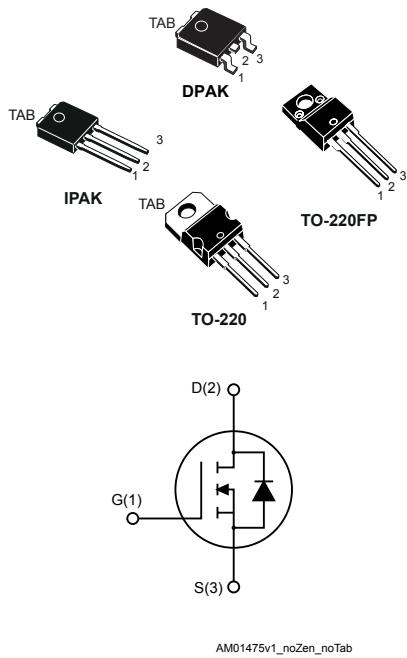


N-channel 800 V, 0.95 Ω typ., 6.5 A MDmesh™ II Power MOSFETs in DPAK, IPAK, TO-220FP and TO-220 packages



Features

| Order codes | V _{DS} | R _{Ds(on)max.} | I _D |
|-------------|-----------------|-------------------------|----------------|
| STD7NM80 | 800 V | 1.05 Ω | 6.5 A |
| STD7NM80-1 | | | |
| STF7NM80 | | | |
| STP7NM80 | | | |

- 100% avalanche tested
- Low input capacitance and gate charge
- Low gate input resistance

Applications

- Switching applications

Description

These devices are N-channel Power MOSFETs developed using the second generation of MDmesh™ technology. These revolutionary Power MOSFETs associate a vertical structure to the company's strip layout to yield one of the world's lowest on-resistance and gate charge. They are therefore suitable for the most demanding high-efficiency converters.

| Product status |
|----------------|
| STD7NM80 |
| STD7NM80-1 |
| STF7NM80 |
| STP7NM80 |

1 Electrical ratings

Table 1. Absolute maximum ratings

| Symbol | Parameter | Value | | Unit |
|--------------------------------|---|-----------------------|--------------------|------|
| | | DPAK, IPAK, TO-220 | TO-220FP | |
| V _{DS} | Drain-source voltage | 800 | | V |
| V _{GS} | Gate-source voltage | | ±30 | V |
| I _D | Drain current (continuous) at T _C = 25 °C | 6.5 | 6.5 ⁽¹⁾ | A |
| I _D | Drain current (continuous) at T _C = 100 °C | 4 | 4 ⁽¹⁾ | A |
| I _{DM} ⁽²⁾ | Drain current (pulsed) | 26 | 26 ⁽¹⁾ | A |
| P _{TOT} | Total dissipation at T _C = 25 °C | 90 | 25 | W |
| V _{ISO} | Insulation withstand voltage (RMS) from all three leads to external heat sink (t = 1 s; T _C = 25 °C) | | 2.5 | kV |
| T _j | Operating junction temperature range | -55 to 150 | | °C |
| T _{stg} | Storage temperature range | | | |

1. Limited by maximum junction temperature.
2. Pulse width limited by safe operating area.

Table 2. Thermal data

| Symbol | Parameter | Value | | | | Unit |
|-------------------------------------|-------------------------------------|-------|------|----------|--------|------|
| | | DPAK | IPAK | TO-220FP | TO-220 | |
| R _{thj-case} | Thermal resistance junction-case | 1.4 | | 5 | 1.4 | °C/W |
| R _{thj-amb} | Thermal resistance junction-ambient | | 100 | | 62.5 | °C/W |
| R _{thj-pcb} ⁽¹⁾ | Thermal resistance junction-pcb | 50 | | | | °C/W |

1. When mounted on 1inch² FR-4 board, 2 oz Cu.

Table 3. Avalanche characteristics

| Symbol | Parameter | Value | Unit |
|-----------------|---|-------|------|
| I _{AS} | Avalanche current, repetitive or not-repetitive (pulse width limited by T _{jmax}) | 1 | A |
| E _{AS} | Single pulse avalanche energy (starting T _j = 25 °C, I _D = I _{AS} , V _{DD} = 50 V) | 240 | mJ |

2 Electrical characteristics

($T_{CASE} = 25^\circ\text{C}$ unless otherwise specified)

Table 4. On/off states

| Symbol | Parameter | Test condition | Min. | Typ. | Max. | Unit |
|---------------------|-----------------------------------|---|------|------|-----------|---------------|
| $V_{(BR)DSS}$ | Drain-source breakdown voltage | $I_D = 1 \text{ mA}, V_{GS} = 0 \text{ V}$ | 800 | | | V |
| I_{DSS} | Zero gate voltage drain current | $V_{GS} = 0 \text{ V}, V_{DS} = 800 \text{ V}$ | | | 10 | μA |
| | | $V_{GS} = 0 \text{ V}, V_{DS} = 800 \text{ V}, T_C = 125^\circ\text{C}^{(1)}$ | | | 100 | μA |
| I_{GSS} | Gate body leakage current | $V_{DS} = 0 \text{ V}, V_{GS} = \pm 30 \text{ V}$ | | | ± 100 | nA |
| $V_{GS(\text{th})}$ | Gate threshold voltage | $V_{DS} = V_{GS}, I_D = 250 \mu\text{A}$ | 3 | 4 | 5 | V |
| $R_{DS(\text{on})}$ | Static drain-source on-resistance | $V_{GS} = 10 \text{ V}, I_D = 3.25 \text{ A}$ | | 0.95 | 1.05 | Ω |

1. Defined by design, not subject to production test.

Table 5. Dynamic

| Symbol | Parameter | Test condition | Min. | Typ. | Max. | Unit |
|-----------|------------------------------|---|------|------|------|----------|
| C_{iss} | Input capacitance | $V_{DS} = 50 \text{ V}, f = 1 \text{ MHz}, V_{GS} = 0 \text{ V}$ | | 620 | - | pF |
| C_{oss} | Output capacitance | | - | 460 | | |
| C_{rss} | Reverse transfer capacitance | | | 15 | | |
| R_g | Gate input resistance | $f = 1 \text{ MHz}$ open drain | - | 7 | - | Ω |
| Q_g | Total gate charge | $V_{DD} = 640 \text{ V}, I_D = 6.5 \text{ A}, V_{GS} = 0 \text{ to } 10 \text{ V}$ (see Figure 17. Test circuit for gate charge behavior) | | 18 | - | nC |
| Q_{gs} | Gate-source charge | | - | 4 | | |
| Q_{gd} | Gate-drain charge | | | 11 | | |

Table 6. Switching times

| Symbol | Parameter | Test condition | Min. | Typ. | Max. | Unit |
|--------------|---------------------|---|------|------|------|------|
| $t_{d(on)}$ | Turn-on delay time | $V_{DD} = 400 \text{ V}, I_D = 3.25 \text{ A}, R_G = 4.7 \Omega, V_{GS} = 10 \text{ V}$ | | 20 | - | ns |
| t_r | Rise time | | | 8 | | |
| $t_{d(off)}$ | Turn-off delay time | | - | 35 | | |
| t_f | Fall time | | | 10 | | |

Table 7. Source-drain diode

| Symbol | Parameter | Test condition | Min. | Typ. | Max. | Unit |
|-----------------|-------------------------------|----------------|------|------|------|------|
| I_{SD} | Source-drain current | | | | 6.5 | A |
| $I_{SDM}^{(1)}$ | Source-drain current (pulsed) | | - | | 26 | |

| Symbol | Parameter | Test condition | Min. | Typ. | Max. | Unit |
|----------------|--------------------------|--|------|------|---------------------|------|
| $V_{SD}^{(2)}$ | Forward on voltage | $I_{SD} = 6.5 \text{ A}, V_{GS} = 0 \text{ V}$ | - | | 1.3 | V |
| t_{rr} | Reverse recovery time | $I_{SD} = 6.5 \text{ A}, di/dt = 100 \text{ V}/\mu\text{s}$ $V_{DD} = 50 \text{ V}$ (see Figure 18. Test circuit for inductive load switching and diode recovery times) | - | 460 | ns μC | |
| Q_{rr} | Reverse recovery charge | | | 4 | | |
| I_{RRM} | Reverse recovery current | | | 17 | | |
| t_{rr} | Reverse recovery time | $I_{SD} = 6.5 \text{ A}, di/dt = 100 \text{ A}/\mu\text{s}$ $V_{DD} = 50 \text{ V}$ (see Figure 18. Test circuit for inductive load switching and diode recovery times) | - | 680 | ns μC | |
| Q_{rr} | Reverse recovery charge | | | 6 | | |
| I_{RRM} | Reverse recovery current | | | 17 | | |

1. Pulse width limited by safe operating area.
2. Pulsed: pulse duration = 300 μs , duty cycle 1.5%.

2.1

Electrical characteristics (curves)

Figure 1. Safe operating area for DPAK and IPAK

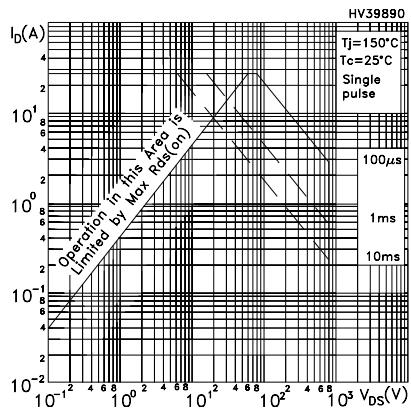


Figure 2. Thermal impedance for DPAK and IPAK

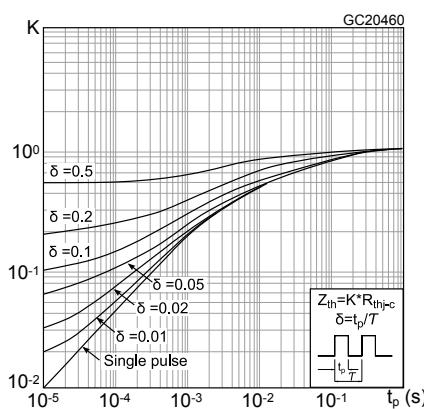


Figure 3. Safe operating area for TO-220FP

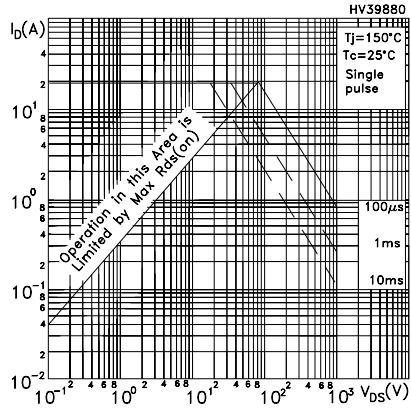


Figure 4. Thermal impedance for TO-220FP

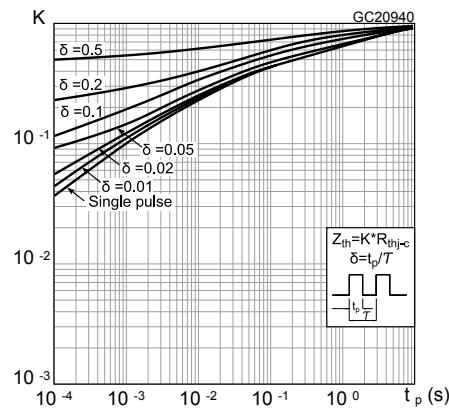


Figure 5. Safe operating area for TO-220

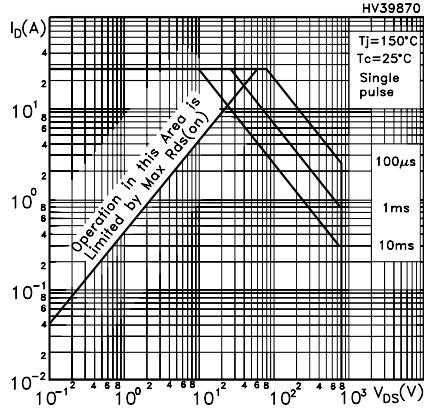


Figure 6. Thermal impedance for TO-220

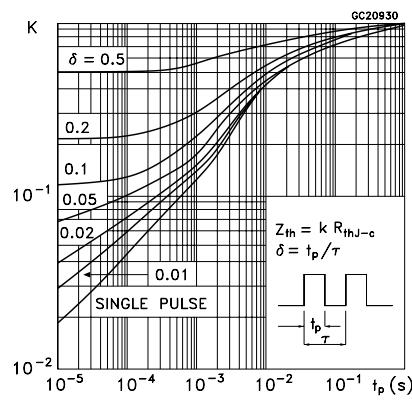


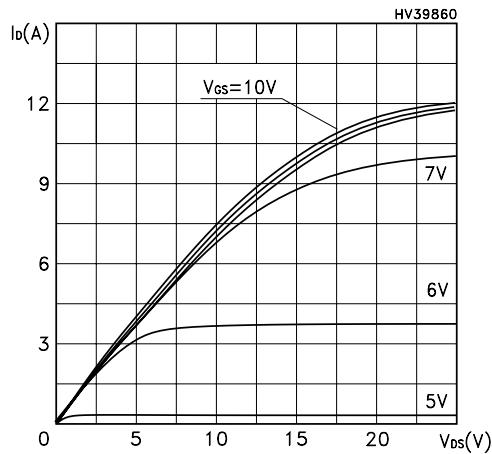
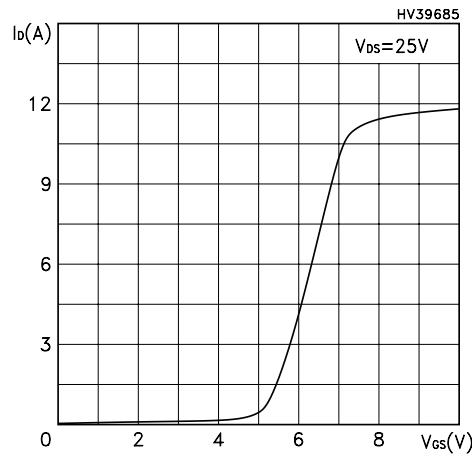
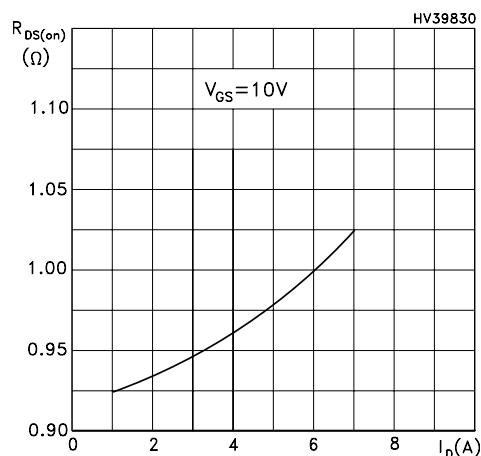
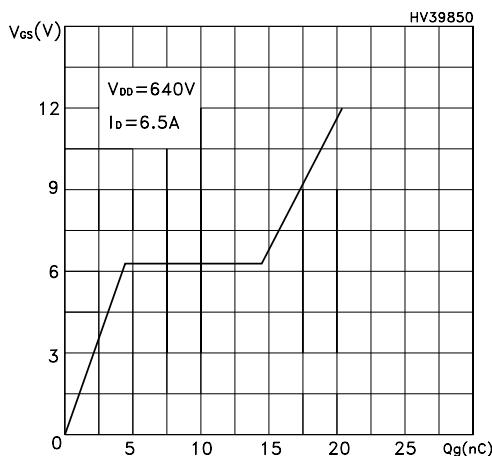
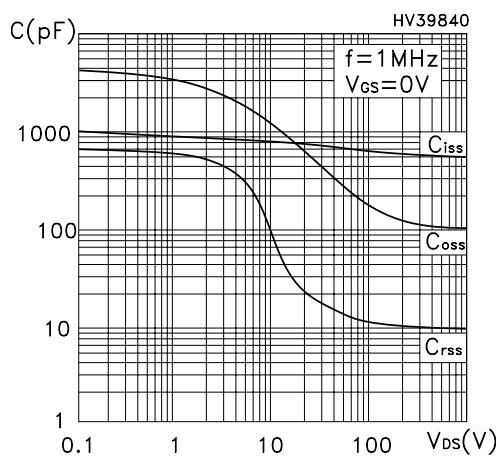
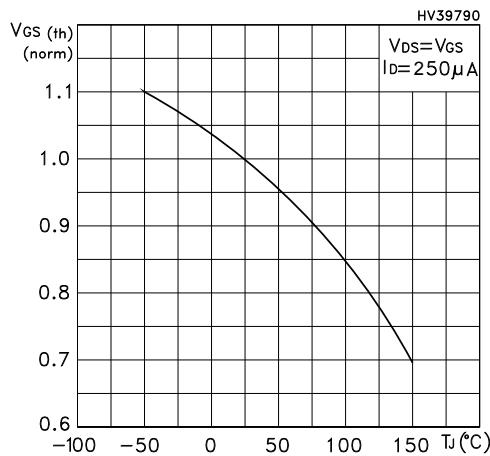
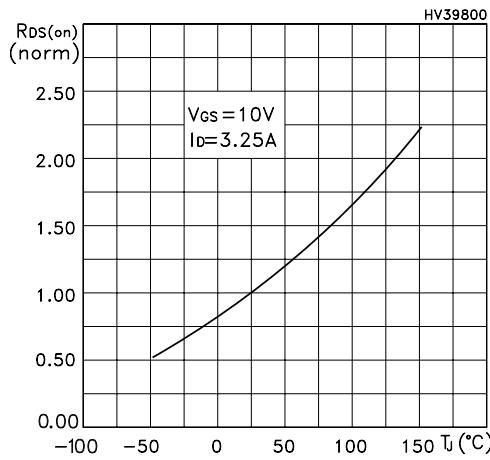
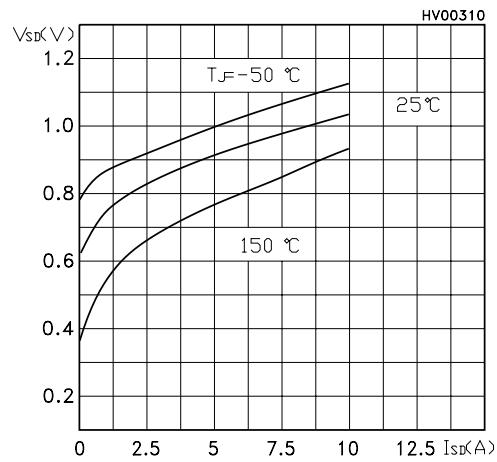
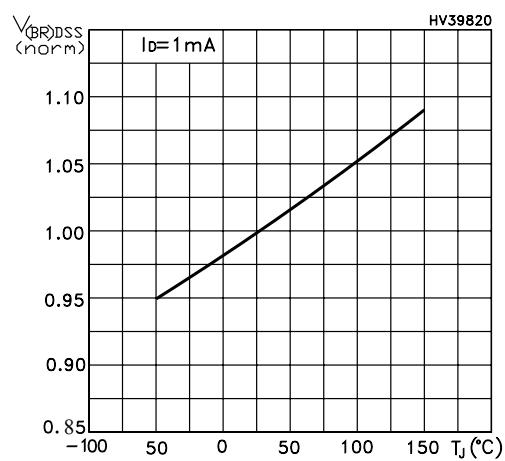
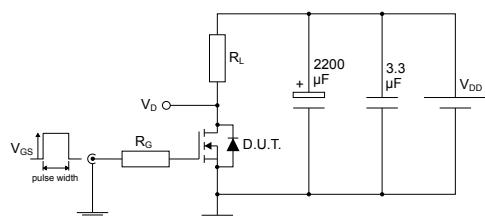
Figure 7. Output characteristics

Figure 8. Transfer characteristics

Figure 9. Static drain-source on-resistance

Figure 10. Gate charge vs gate-source voltage

Figure 11. Capacitance variations

Figure 12. Normalized gate threshold voltage vs temperature


Figure 13. Normalized on-resistance vs temperature

Figure 14. Source-drain diode forward characteristics

Figure 15. Normalized $V_{(BR)DSS}$ vs temperature


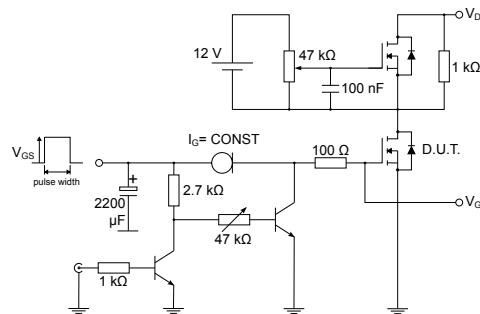
3 Test circuits

Figure 16. Test circuit for resistive load switching times



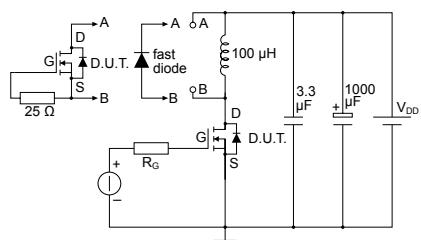
AM01468v1

Figure 17. Test circuit for gate charge behavior



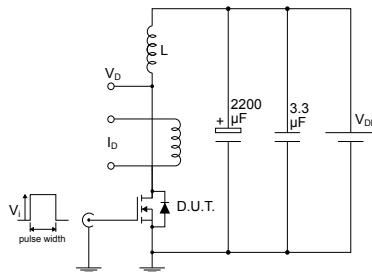
AM01469v1

Figure 18. Test circuit for inductive load switching and diode recovery times



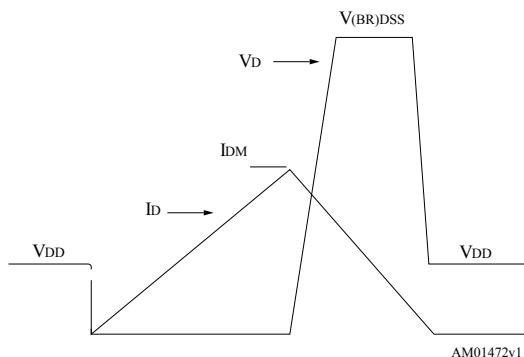
AM01470v1

Figure 19. Unclamped inductive load test circuit



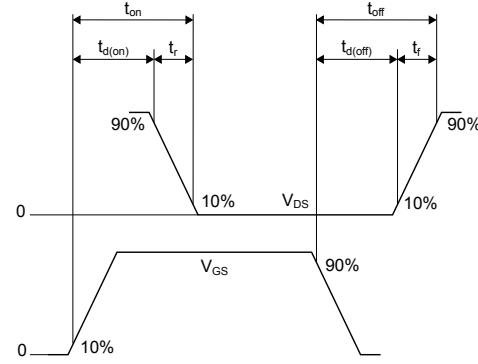
AM01471v1

Figure 20. Unclamped inductive waveform



AM01472v1

Figure 21. Switching time waveform



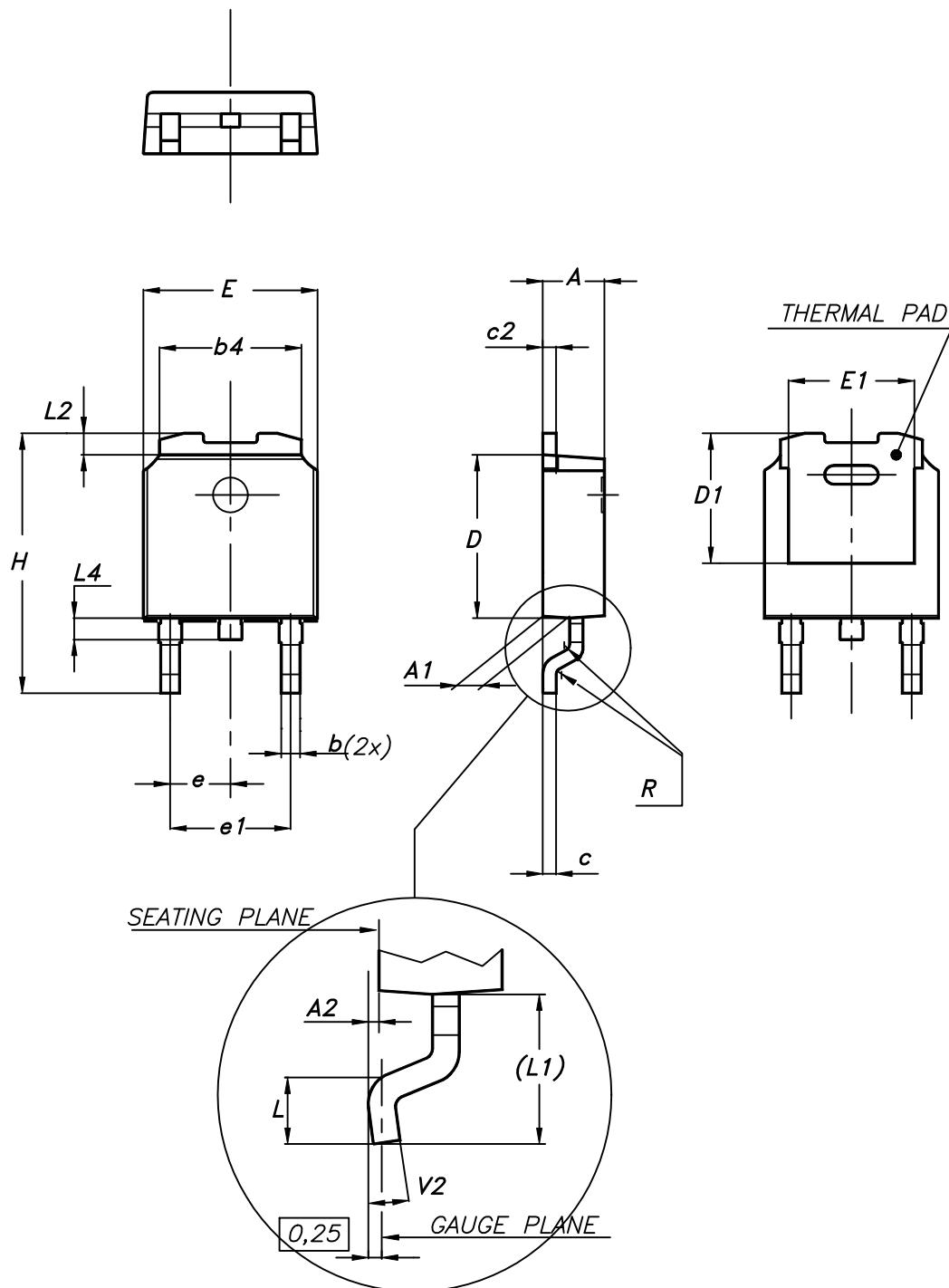
AM01473v1

4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

4.1 DPAK (TO-252) type A2 package information

Figure 22. DPAK (TO-252) type A2 package outline

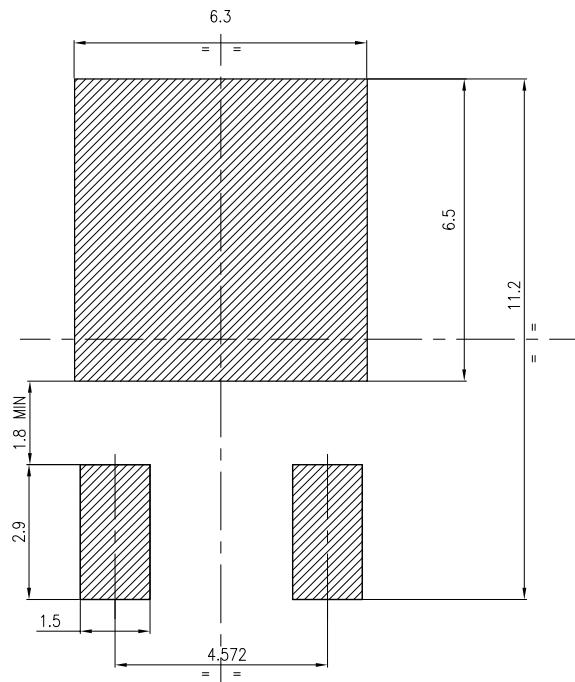


0068772_type-A2_rev25

Table 8. DPAK (TO-252) type A2 mechanical data

| Dim. | mm | | |
|------|-------|-------|-------|
| | Min. | Typ. | Max. |
| A | 2.20 | | 2.40 |
| A1 | 0.90 | | 1.10 |
| A2 | 0.03 | | 0.23 |
| b | 0.64 | | 0.90 |
| b4 | 5.20 | | 5.40 |
| c | 0.45 | | 0.60 |
| c2 | 0.48 | | 0.60 |
| D | 6.00 | | 6.20 |
| D1 | 4.95 | 5.10 | 5.25 |
| E | 6.40 | | 6.60 |
| E1 | 5.10 | 5.20 | 5.30 |
| e | 2.159 | 2.286 | 2.413 |
| e1 | 4.445 | 4.572 | 4.699 |
| H | 9.35 | | 10.10 |
| L | 1.00 | | 1.50 |
| L1 | 2.60 | 2.80 | 3.00 |
| L2 | 0.65 | 0.80 | 0.95 |
| L4 | 0.60 | | 1.00 |
| R | | 0.20 | |
| V2 | 0° | | 8° |

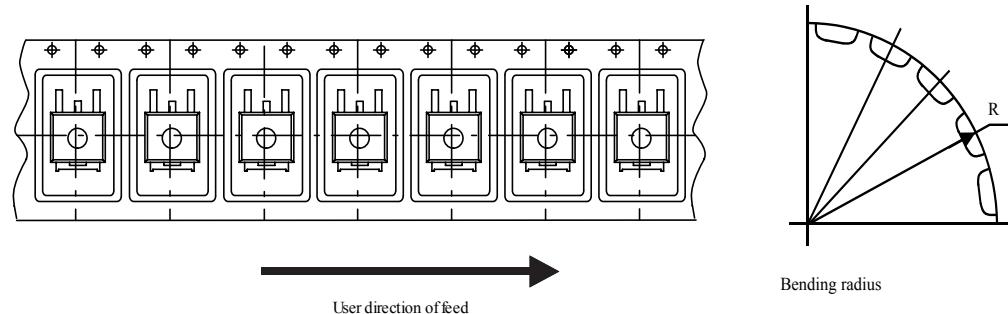
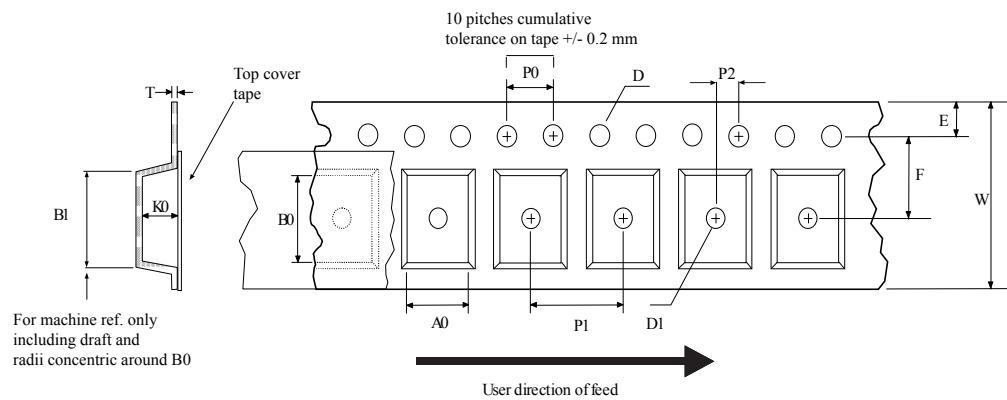
Figure 23. DPAK (TO-252) recommended footprint (dimensions are in mm)



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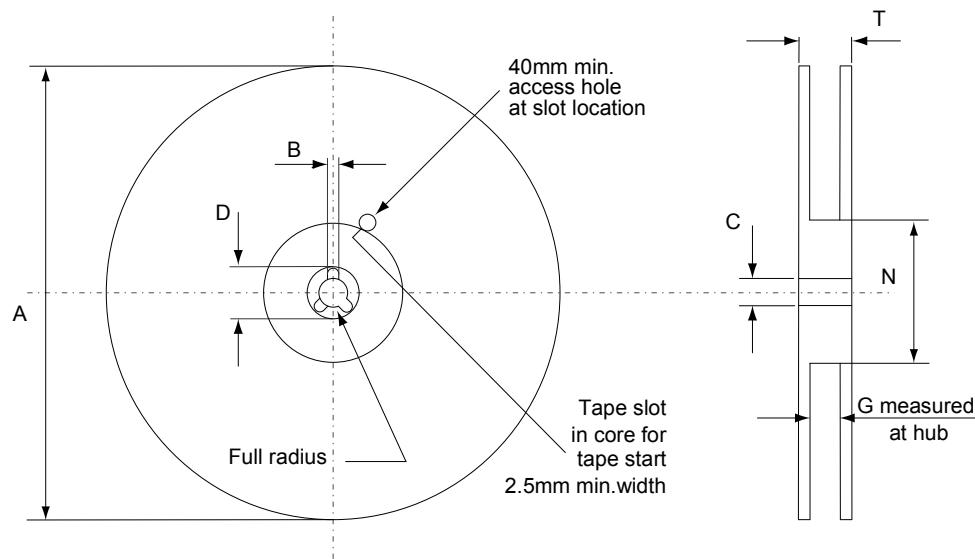
4.2 DPAK (TO-252) packing information

Figure 24. DPAK (TO-252) tape outline



Bending radius

AM08852v1

Figure 25. DPAK (TO-252) reel outline


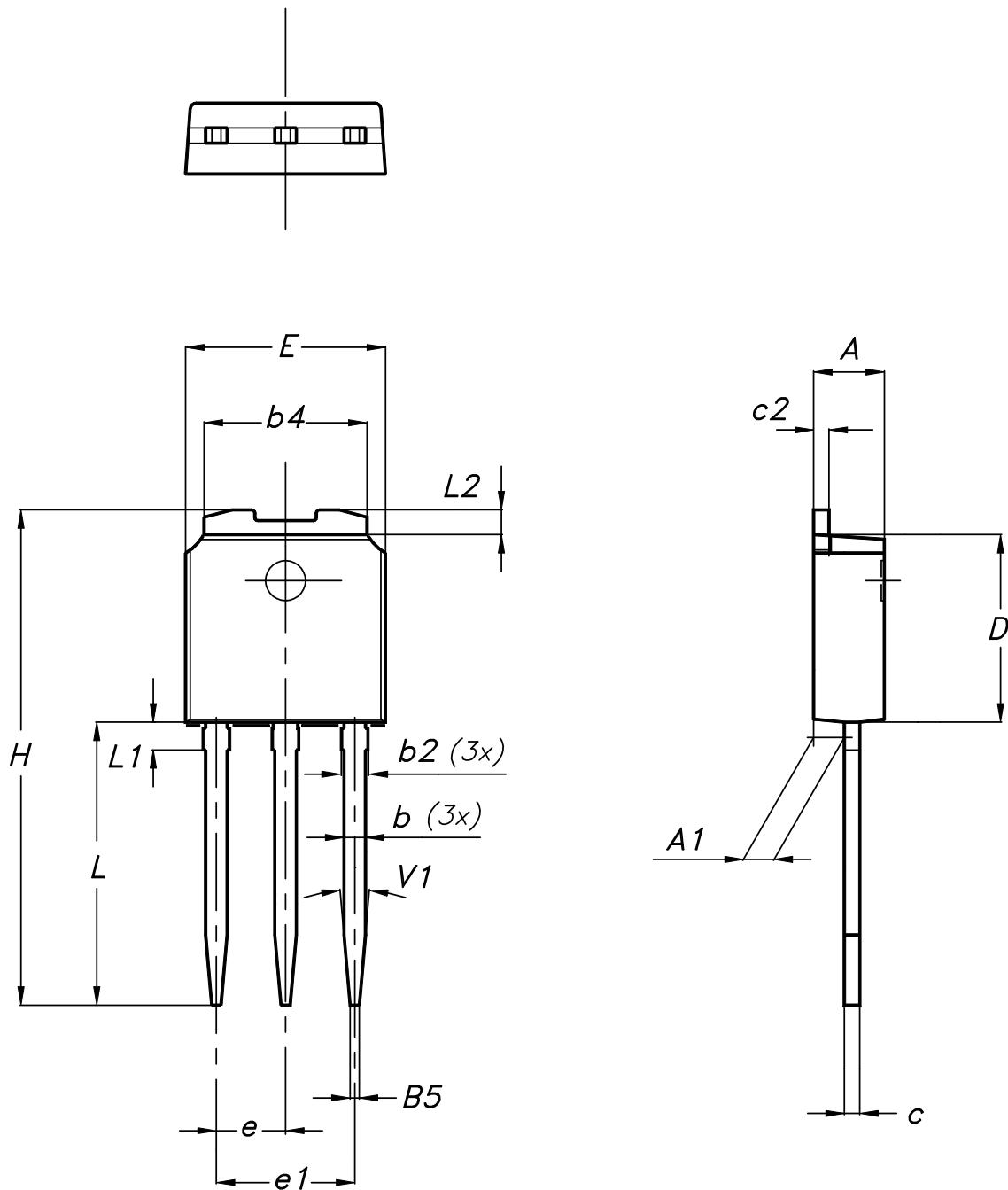
AM06038v1

Table 9. DPAK (TO-252) tape and reel mechanical data

| Tape | | | Reel | | |
|------|------|------|-----------|------|------|
| Dim. | mm | | Dim. | mm | |
| | Min. | Max. | | Min. | Max. |
| A0 | 6.8 | 7 | A | | 330 |
| B0 | 10.4 | 10.6 | B | 1.5 | |
| B1 | | 12.1 | C | 12.8 | 13.2 |
| D | 1.5 | 1.6 | D | 20.2 | |
| D1 | 1.5 | | G | 16.4 | 18.4 |
| E | 1.65 | 1.85 | N | 50 | |
| F | 7.4 | 7.6 | T | | 22.4 |
| K0 | 2.55 | 2.75 | | | |
| P0 | 3.9 | 4.1 | Base qty. | | 2500 |
| P1 | 7.9 | 8.1 | Bulk qty. | | 2500 |
| P2 | 1.9 | 2.1 | | | |
| R | 40 | | | | |
| T | 0.25 | 0.35 | | | |
| W | 15.7 | 16.3 | | | |

4.3 IPAK (TO-251) type A package information

Figure 26. IPAK (TO-251) type A package outline



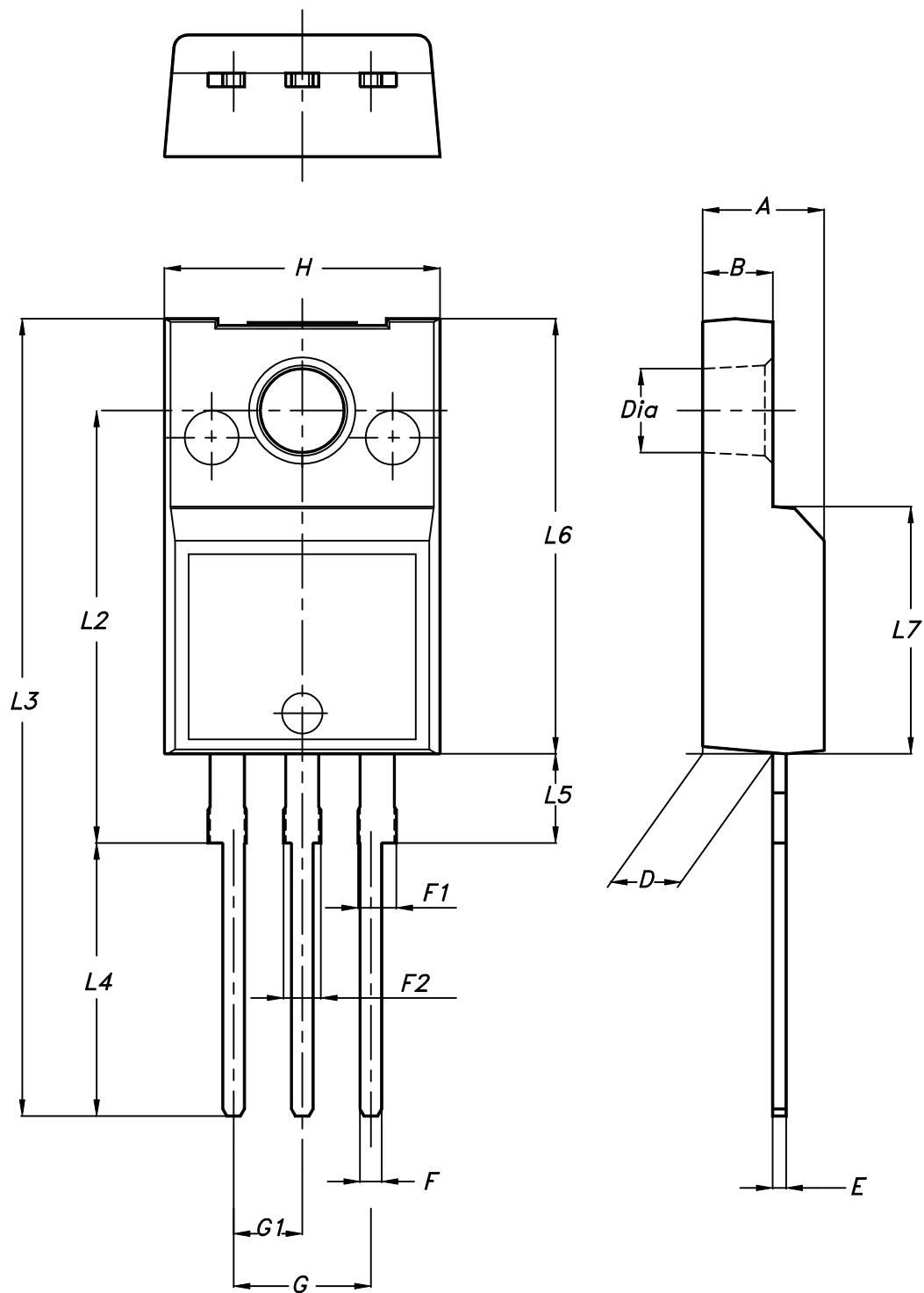
0068771_IK_typeA_rev14

Table 10. IPAK (TO-251) type A package mechanical data

| Dim. | mm | | |
|------|------|-------|------|
| | Min. | Typ. | Max. |
| A | 2.20 | | 2.40 |
| A1 | 0.90 | | 1.10 |
| b | 0.64 | | 0.90 |
| b2 | | | 0.95 |
| b4 | 5.20 | | 5.40 |
| B5 | | 0.30 | |
| c | 0.45 | | 0.60 |
| c2 | 0.48 | | 0.60 |
| D | 6.00 | | 6.20 |
| E | 6.40 | | 6.60 |
| e | | 2.28 | |
| e1 | 4.40 | | 4.60 |
| H | | 16.10 | |
| L | 9.00 | | 9.40 |
| L1 | 0.80 | | 1.20 |
| L2 | | 0.80 | 1.00 |
| V1 | | 10° | |

4.4 TO-220FP package information

Figure 27. TO-220FP package outline



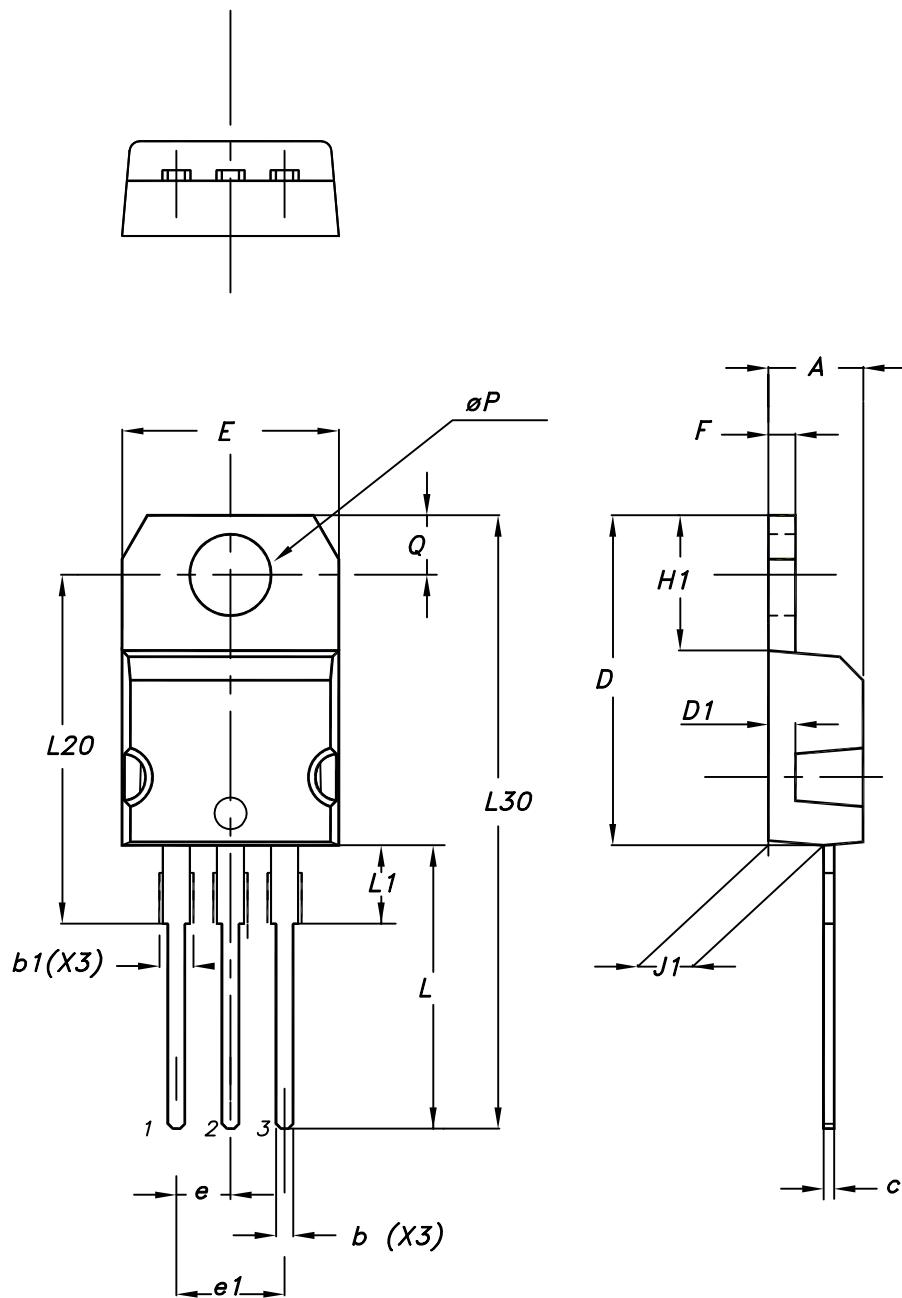
7012510_Rev_12_B

Table 11. TO-220FP package mechanical data

| Dim. | mm | | |
|------|------|------|------|
| | Min. | Typ. | Max. |
| A | 4.4 | | 4.6 |
| B | 2.5 | | 2.7 |
| D | 2.5 | | 2.75 |
| E | 0.45 | | 0.7 |
| F | 0.75 | | 1 |
| F1 | 1.15 | | 1.70 |
| F2 | 1.15 | | 1.70 |
| G | 4.95 | | 5.2 |
| G1 | 2.4 | | 2.7 |
| H | 10 | | 10.4 |
| L2 | | 16 | |
| L3 | 28.6 | | 30.6 |
| L4 | 9.8 | | 10.6 |
| L5 | 2.9 | | 3.6 |
| L6 | 15.9 | | 16.4 |
| L7 | 9 | | 9.3 |
| Dia | 3 | | 3.2 |

4.5 TO-220 type A package information

Figure 28. TO-220 type A package outline



0015988_typeA_Rev_21

Table 12. TO-220 type A package mechanical data

| Dim. | mm | | |
|------|-------|-------|-------|
| | Min. | Typ. | Max. |
| A | 4.40 | | 4.60 |
| b | 0.61 | | 0.88 |
| b1 | 1.14 | | 1.55 |
| c | 0.48 | | 0.70 |
| D | 15.25 | | 15.75 |
| D1 | | 1.27 | |
| E | 10.00 | | 10.40 |
| e | 2.40 | | 2.70 |
| e1 | 4.95 | | 5.15 |
| F | 1.23 | | 1.32 |
| H1 | 6.20 | | 6.60 |
| J1 | 2.40 | | 2.72 |
| L | 13.00 | | 14.00 |
| L1 | 3.50 | | 3.93 |
| L20 | | 16.40 | |
| L30 | | 28.90 | |
| øP | 3.75 | | 3.85 |
| Q | 2.65 | | 2.95 |

5 Ordering information

Table 13. Order codes

| Order code | Marking | Package | Packing |
|------------|---------|----------|---------------|
| STD7NM80 | D7NM80 | DPAK | Tape and reel |
| STD7NM80-1 | D7NM80 | IPAK | |
| STF7NM80 | F7NM80 | TO-220FP | Tube |
| STP7NM80 | P7NM80 | TO-220 | |

Revision history

Table 14. Document revision history

| Date | Version | Changes |
|-------------|---------|--|
| 22-Sep-2006 | 1 | First release. |
| 09-Oct-2007 | 2 | Added new section: <i>Electrical characteristics (curves)</i> . |
| 02-Oct-2009 | 3 | Corrected marking and description on first page. |
| 20-Aug-2018 | 4 | Updated Section 4 Package information . Minor text changes. |

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| | Revision history | 22 |



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